ON Semiconductor

Is Now

Onsemi

To learn more about onsemi[™], please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI: and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application is provided for uses as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi roducts for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs

N-Channel Power MOSFET 500 V, 3.3 Ω

Features

- Low ON Resistance
- Low Gate Charge
- ESD Diode-Protected Gate

Rating

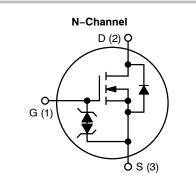
- 100% Avalanche Tested
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



ON Semiconductor®

http://onsemi.com

V _{DSS}	R _{DS(on)} (MAX) @ 1.15 A
500 V	3.3 Ω





ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Symbol

Value

Unit

Drain-to-Source Voltage	V _{DSS}	500	V
Continuous Drain Current $R_{\theta JC}$	Ι _D	2.6	А
Continuous Drain Current $R_{\theta JC}$, $T_A = 100^{\circ}C$	۱ _D	1.7	A
Pulsed Drain Current, $V_{GS} \mathbin{@} 10 \ V$	I _{DM}	10	А
Power Dissipation $R_{\theta JC}$	PD	58	W
Gate-to-Source Voltage	V _{GS}	±30	V
Single Pulse Avalanche Energy, $I_D = 2.6 A$	E _{AS}	120	mJ
ESD (HBM) (JESD22-A114)	V _{esd}	2000	V
Peak Diode Recovery	dv/dt	4.5 (Note 1)	V/ns
Continuous Source Current (Body Diode)	I _S	2.6	A
Maximum Temperature for Soldering Leads	ΤL	260	°C
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. $I_D \leq 2.6$ A, di/dt ≤ 200 A/ μ s, V_{DD} \leq BV_{DSS}, T_J $\leq 150^{\circ}$ C.

MARKING AND ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

THERMAL RESISTANCE

Parameter			Value	Unit
Junction-to-Case (Drain)	NDD03N50Z	$R_{\theta JC}$	2.2	°C/W
Junction-to-Ambient Steady State	(Note 3) NDD03N50Z (Note 2) NDD03N50Z-1	R_{\thetaJA}	41 80	

2. Insertion mounted

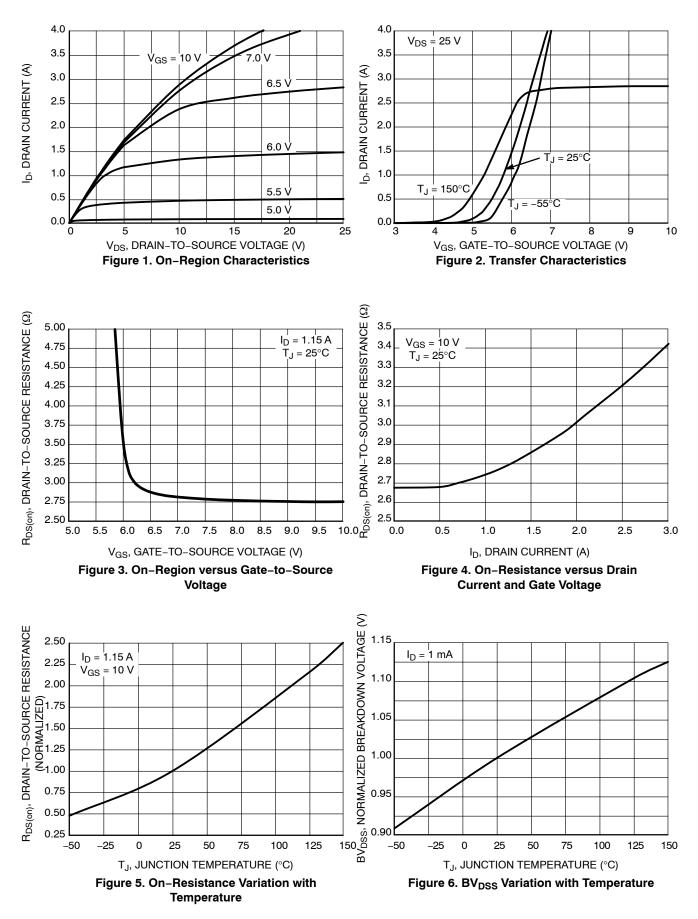
3. Surface mounted on FR4 board using 1" sq. pad size, (Cu area = 1.127 in sq [2 oz] including traces).

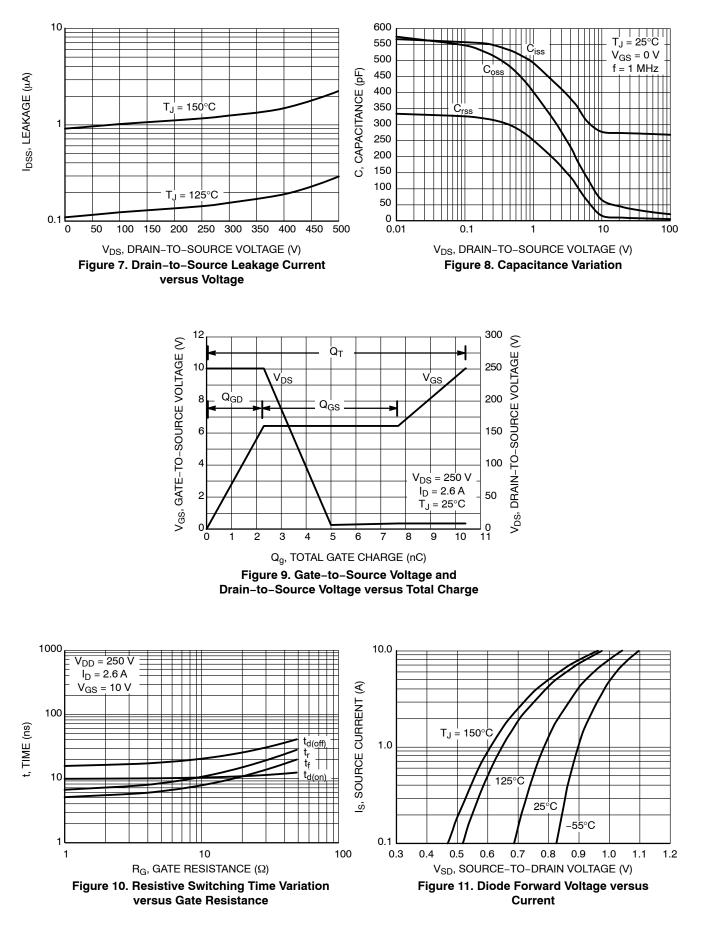
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

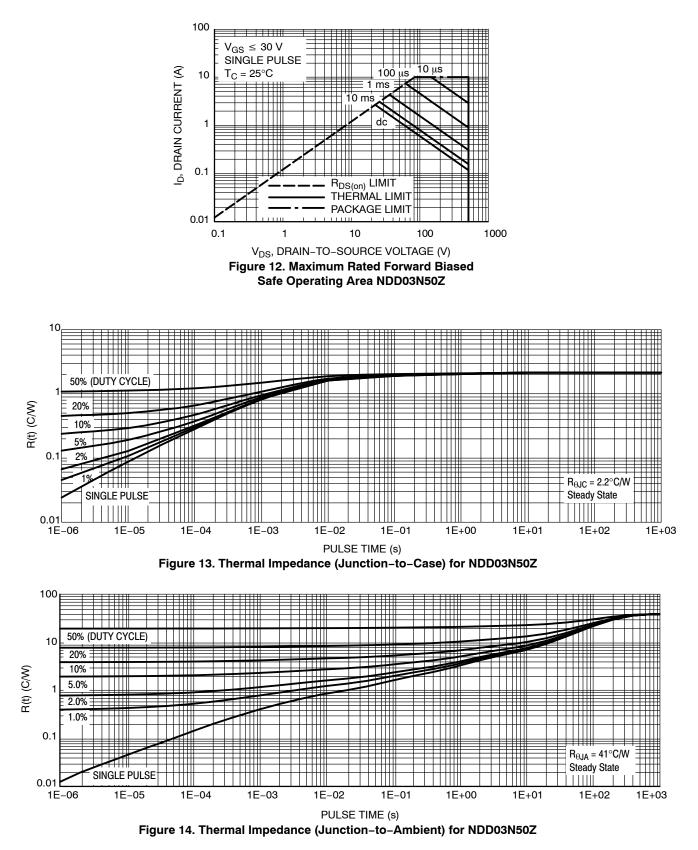
Characteristic	Symbol	Test Conditions		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0 V, I _D = 1 m	ıΑ	500			V
Breakdown Voltage Temperature Coefficient	$\Delta \text{BV}_{\text{DSS}}/$ $\Delta \text{T}_{\text{J}}$	Reference to 25°C I _D = 1 mA),		0.6		V/°C
Drain-to-Source Leakage Current	I _{DSS}		25°C			1.0	μA
		$V_{DS} = 500 \text{ V}, V_{GS} = 0 \text{ V}$	150°C			50	1
Gate-to-Source Forward Leakage	I _{GSS}	V _{GS} = ±20 V				±10	μA
ON CHARACTERISTICS (Note 4)					-	-	-
Static Drain-to-Source On-Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 1.1	5 A		2.8	3.3	Ω
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 50$	μA	3.0		4.5	V
Forward Transconductance	9 _{FS}	V _{DS} = 15 V, I _D = 1.1	5 A		1.8		S
DYNAMIC CHARACTERISTICS							
Input Capacitance (Note 5)	C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		219	274	329	pF
Output Capacitance (Note 5)	C _{oss}			28	38	50	
Reverse Transfer Capacitance (Note 5)	C _{rss}			6.0	8.0	10	
Total Gate Charge (Note 5)	Qg			5.0	10	16	nC
Gate-to-Source Charge (Note 5)	Q _{gs}	V _{DD} = 250 V, I _D = 2.6	6 A,	1.2	2.3	4.0	1
Gate-to-Drain ("Miller") Charge (Note 5)	Q _{gd}	V _{GS} = 10 V	-	3.2	5.5	8.0	1
Plateau Voltage	V _{GP}				6.4		V
Gate Resistance	R _g			1.5	4.5	13.5	Ω
RESISTIVE SWITCHING CHARACTERISTI	cs						
Turn-On Delay Time	t _{d(on)}				9.0		ns
Rise Time	t _r	V_{DD} = 250 V, I_D = 2.6 A, V_{GS} = 10 V, R_G = 5 Ω			7.0		1
Turn-Off Delay Time	t _{d(off)}				15		1
Fall Time	t _f				7.0		1

Diode Forward Voltage	V _{SD}	$I_{\rm S}$ = 2.6 A, $V_{\rm GS}$ = 0 V		1.6	V
Reverse Recovery Time	t _{rr}	$V_{GS} = 0 V, V_{DD} = 30 V$	240		ns
Reverse Recovery Charge	Q _{rr}	I _S = 2.6 A, di/dt = 100 A/μs	0.7		μC

4. Pulse Width \leq 380 μ s, Duty Cycle \leq 2%. 5. Guaranteed by design.





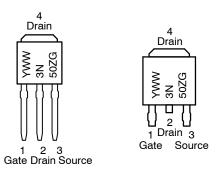


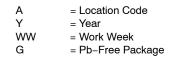
ORDERING INFORMATION

Order Number	Package	Shipping [†]
NDD03N50Z-1G	IPAK (Pb-Free)	75 Units / Rail
NDD03N50ZT4G	DPAK (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS





SCALE 1:1

STYLE 1: PIN 1. BASE

2. COLLECTOR

4. COLLECTOR

3. EMITTER

STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE

4. ANODE

DATE 15 DEC 2010



IPAK CASE 369D-01 **ISSUE C** С в -ν Ε R 7 4 Α S 2 3 1 -T-7 SEATING PLANE κ J F ·H D 3 PL G 🖛 🔶 0.13 (0.005) 🔘 T

> STYLE 3: PIN 1. ANODE

2. CATHODE

4. CATHODE

COLLECTOR

3. ANODE

STYLE 7: PIN 1. GATE 2. COLLECTOR 3. EMITTER

4.

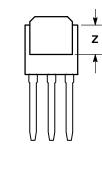
STYLE 2: PIN 1. GATE

STYLE 6: PIN 1. MT1 2. MT2 3. GATE

4. MT2

DRAIN
 SOURCE

4. DRAIN



STYLE 4: PIN 1. CATHODE

ANODE
 GATE

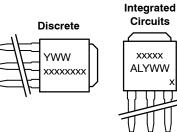
4. ANODE

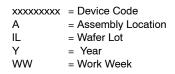
	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29	BSC
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
κ	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Ζ	0.155		3.93	

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.

NOTES:

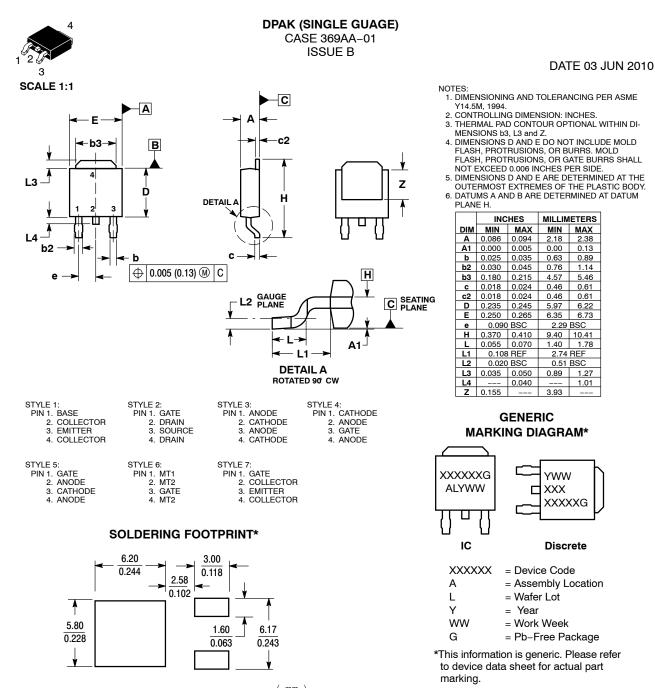
MARKING DIAGRAMS





DOCUMENT NUMBER:	98AON10528D	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION: IPAK (DPAK INSERTION MOUNT) PAGE 1 OF 1					
ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the					





SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER: 98AON13126D Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. DESCRIPTION: DPAK (SINGLE GAUGE) PAGE 1 OF 1 ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or cricuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the

© Semiconductor Components Industries, LLC, 2019

rights of others

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor and the support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconducts harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized claim alleges that

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

٥